



# **NMOS multichannel detector head**

C5964 series

## UV to near infrared range (200 to 1000 nm), For multichannel spectrophotometry

The C5964 series is a family of multichannel detectors developed for spectrophotometry in the UV to near infrared range (up to 1000 nm). The C5964 series device incorporates a thermoelectrically-cooled NMOS linear image sensor (S5930/S5931/S8382/S8383 series), low noise driver/amplifier circuit and highly stable temperature control circuit. It also operates from simple external signal inputs. The image sensor is cooled to a preset temperature (Ts=0 °C) as soon as the power is turned on. Should the cooler fail and the device overheat, the built-in protection circuit automatically shut off the power. The housing is designed for compactness, yet offers good heart dissipation. Furthermore, mounting holes are provided on the front panel of the housing, permitting easy connection to a monochromator or other instruments

#### - Features

- Designed for use with a thermoelectrically-cooled NMOS linear image sensors (S5930 series, etc.)
- Built-in driver/amplifier and temperature control circuits
- ➡ Highly stable temperature control ensures a constant cooling temperature of Ts=0 ± 0.05 °C (at Ta=10 to 30 °C)
- Operates from simple signal inputs
- High sensitivity and wide dynamic range

#### - Applications

- Multichannel spectrophotometry
- Spectrophotometer, colorimeter
- Optical spectrum analyzer
- Time-resolved photometry

#### Selection guide

The C5964 series consists of the following models depending on the NMOS linear image sensor used.

NMOS	NMOS linear image sensor					
multichannel	Type No.	Number of nivels	Pixel size Effective active are		Remark	
detector head	туре но.	Number of pixels	[µm (H) × µm (V)]	[mm (H) × mm (V)]	Reifidik	
C5964-0800	S5930-256S	256	50 × 2500	12.8 × 2.5		
C5964-0900	S5930-512S	512	50 × 2500	25.6 × 2.5	Standard type	
C5964-0910	S5931-512S	512	25 × 2500	12.8 × 2.5	Stanuaru type	
C5964-1010	S5931-1024S	1024	25 × 2500	25.6 × 2.5		
C5964-0901	S8382-512S	512	50 × 2500	25.6 × 2.5	IR-enhanced type	
C5964-1011	S8383-1024S	1024	25 × 2500	25.6 × 2.5	IN-enhanced type	

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## Connection example



KACCC0070ED

#### **Precaution for use**

When operating the C5964 series with the C7557-01, always be sure to attach the MOS adapter (supplied) to the C7557-01 main unit. If the the C5964 series is connected and the power is turned on without attaching the adapter, the power supply in the C7557-01 main unit may be damaged.

#### Absolute maximum ratings

Parameter	Symbol	Value	Unit
Supply voltage (for digital circuitry)	+VD	-0.5 to +7	V
Supply voltage (for analog circuitry)	±VA	±18	V
Digital input voltage	-	VD	V
Operating temperature	Topr	+10 to +30	°C
Storage temperature	Tstg	0 to +50	°C

#### Electrical characteristics (Ta=25 °C, VD=+5 V, ±VA=±15 V, unless otherwise noted)

Parameter			Symbol	Min.	Тур.	Max.	Unit
		High level	VIH	+2.0	-	+VD	V
		Low level	VIL	-0.5	-	+0.8	V
Master clock (CLK	) pulse frequency		<b>f</b> CLK	-	-	375	kHz
Video signal reado	out frequency		fv	-	-	fclk/6	Hz
Master start (Start) pulse width			tst	1/fclk	-	-	S
Digital outputHigh level (Io=-6 mA)Low level (Io=+6 mA)		VIH	+2.0	-	-	V	
		Low level (Io=+6 mA)	VIL	-	-	+0.8	V
Power supply	Dated voltage	Digital	+VD	+4.75	+5.0	+5.25	V
	Rated voltage	Analog	±VΑ	±14.5	±15.0	±15.5	V
		+5 Vdc *1	-	-	-	+2.0	A
	Current consumption	+15 Vdc	-	-	-	+100	mA
		-15 Vdc	-	-	-	-100	mA

\*1: Including the current consumption of the Peltier element incorporated in the NMOS linear image sensors (S5930 series, etc.)



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Parameter	Built in sensor	Symbol	Min.	Тур.	Max.	Unit
Spectral response range		λ	-	200 to 1000	-	nm
Peak sensitivity wavelength	S5930/S5931 series	10	-	600	-	nm
Peak sensitivity wavelength	S8382/S8383 series	λр	-	750	-	
	S5930 series		-	50	-	pC
Saturation output charge	S5931 series	Ocat	-	25	-	
Saturation output charge	S8382 series	– Qsat	-	50	-	
	S8383 series	1	-	25	-	
	S5930 series		-	0.009	0.03	pA/pixel
Dark current	S5931 series		-	0.004	0.01	
Dark current	S8382 series	- Id	-	0.009	0.03	
	S8383 series		-	0.004	0.01	
Photo response non-uniformity *2		PRNU	-	-	±3	%
	S5930 series		-	0.2	-	V/pC
Conversion gain	S5931 series		-	0.4	-	
Conversion gain	S8382 series	Gc	-	0.2	-	
	S8383 series		-	0.4	-	

\*2: Use for "A" light source. 50 % of saturation, excluding first and last pixels.

#### Temperature controller specifications (Ta=25 °C, VD=+5 V, ±VA=±15 V, unless otherwise noted)

Parameter *3	Symbol	Min.	Тур.	Max.	Unit
Cooling temperature	Ts	-1	0	+1	°C
Temperature control range	ΔTs	-0.05	-	+0.05	°C
Power dissipation of Peltier element	Рр	-	-	7	W
Cool down time to preset temperature	to	-	-	5	min
Setting temperature for overheart protection	То	+40	-	-	°C

\*3: Other functions include error display, automatic power off, and detection of electrical opens and shorts by the thermosensor.



#### Spectral response (Measurement example)

KMPDB0159EA





#### Equivalent circuit (NMOS linear image sensor S5930/S5931/S8382/S8383 series)

#### Block diagram (C5964 series)



\*1: Thermistor incorporated in the image sensor (for temperature monitoring of the image sensor) \*2: Thermistor mounted on the heatsink fins (for temperature monitoring of the heat radiating side)



KACCC0067EA

### Timing chart

CLK Start	
ST CLK1/Reset CLK2 Reset CLK2/Clamp Trigger	
Data video	

## Dimensional outline (unit: mm)





#### Pin connection

15-pin D-sub connector (socket type)



KACCC0069EA

Pin No.	Symbol	Description
1	NC	No connection
2	Data video	Analog video output signal. Positive polarity
3	VA1+(+15 V)	Power supply for analog circuitry
4	Va1-(-15 V)	Power supply for analog circuitry
5	VD(+5 V, P+)	Power supply for digital circuitry. For the thermoelectric cooler in the NMOS linear image sensor
6	Start	Digital input signal to initialize the circuit HCMOS compatible. Positive logic The start pulse interval determines the signal storage time of the sensor.
7	CLK	Digital input signal to specify the circuit operation HCMOS compatible. Operates at the rising edge
8	EOS	Digital output signal to indicate the end of scan of the NMOS linear image sensor HCMOS compatible. Negative logic
9	A.GND	Analog ground
10	A.GND	Analog ground
11	NC	No connection
12	D.GND(P-)	Digital ground. Power supply return of the thermoelectric cooler mounted in the NMOS linear image sensor
13	D.GND	Digital ground
14	D.GND	Digital ground
15	Trigger	Digital output signal for A/D conversion HCMOS compatible. Positive logic

#### Precautions for use

The C5964 series is a precision device, so use sufficient caution when handling it.

- Never disassemble or modify the device as this may cause an operating failure.
- Protect the device from shocks such as drops or impacts.
- Avoid storing the device in high temperature and high humidity locations for long periods of time.
- Never block the air vents provided on the top and side panels of this unit during operation. Blocking the air vents may cause overheating.
- When connecting to other equipment, check that the electrical specifications are matched.
- Never exceed the maximum ratings during operation.
  Observe the following precautions to obtain the fullest performance of device.
- Provide a proper shield to protect the device against external electromagnetic effects. Use of a shield cable is recommended.
- Use a power supply with minimum ripple and noise.
- Pay attention to prevent extraneous light from entering the device for accurate measurements.



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Information described in this material is current as of July, 2014.

Product specifications are subject to change without prior notice due to improvements or other reasons. This document has been carefully prepared and the information contained is believed to be accurate. In rare cases, however, there may be inaccuracies such as text errors. Before using these products, always contact us for the delivery specification sheet to check the latest specifications.

The product warranty is valid for one year after delivery and is limited to product repair or replacement for defects discovered and reported to us within that one year period. However, even if within the warranty period we accept absolutely no liability for any loss caused by natural disasters or improper product use.

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